



SDI FINAL EVALUATION FORM 1.1

PART 1:

Journal Name:	Physical Science International Journal
Manuscript Number:	2015_PSIJ_18553
Title of the Manuscript:	Electrical and photoelectric properties of crystal InGaTe2

PART 2:

FINAL EVALUATOR'S comments on revised paper (if any)	Authors' response to final evaluator's comments
<p>Standard of English correction is still very poor. 1st sentence of introduction line no 20-21 "Complex semiconductor compounds of the class are interesting as a material for recieves of radiation" is not clearly written.</p> <p>Similar sentences are also present in the text. I feel this paper should be rejected</p>	

Reviewer Details:

Name:	Anonymous
Department, University & Country	N.S.N. Research Center for Nanotechnology & Bionanotechnology, Ambernath, India